2N918

NPN SILICON RF TRANSISTOR



www.centralsemi.com

DESCRIPTION:

The CENTRAL SEMICONDUCTOR 2N918 type is an NPN silicon RF transistor, manufactured by the epitaxial planar process and designed for high frequency amplifier and oscillator applications.

MARKING: FULL PART NUMBER



 V_{CB} =15V, I_{C} =8.0mA, f=500MHz

 V_{CB} =12V, I_{C} =6.0mA, f=200MHz

 V_{CB} =15V, I_{C} =8.0mA, f=500MHz

$$\label{eq:CE=0.0V} \begin{split} &V_{CE}\text{=}6.0\text{V}, \text{ }I_{C}\text{=}1.0\text{mA}, \\ &R_{G}\text{=}400\Omega, \text{ }f\text{=}60\text{kHz} \end{split}$$

 P_0

 G_{pe}

η

NF

MAXIMUM F	RATINGS: (T _A =25°C unless otherwise	e noted) SYMBOL		UNITS
Collector-Base Voltage		V _{CBO}	30	V
Collector-Emitter Voltage		V _{CEO}	15	V
Emitter-Base Voltage		V _{EBO}	3.0	V
Continuous Collector Current		IC	50	mA
Power Dissipation		P_{D}	200	mW
Power Dissipation (T _C =25°C)		P_{D}	300	mW
Operating and Storage Junction Temperature		T _J , T _{stq}	-65 to +200	°C
Thermal Resistance		Θ_{JA}	87.5	°C/W
Thermal Resistance		$\Theta_{\sf JC}$	58.3	°C/W
ELECTRICA	L CHARACTERISTICS: (T _A =25°C ur	aless otherwise no	oted)	
SYMBOL				
STWIDOL	TEST CONDITIONS	MIN	MAX	UNITS
ICBO	V _{CB} =15V	IVIIN	MAX 10	nA
		MIN		
I _{CBO}	V _{CB} =15V V _{CB} =15V, T _A =150°C	MIN 30	10	nA
I _{CBO}	V _{CB} =15V V _{CB} =15V, T _A =150°C I _C =1.0μA		10	nA μA
ICBO ICBO BVCBO BVCEO	V _{CB} =15V V _{CB} =15V, T _A =150°C I _C =1.0μA	30	10	nA μA V
ICBO ICBO BVCBO BVCEO BVEBO	V_{CB} =15V V_{CB} =15V, T_{A} =150°C I_{C} =1.0 μ A I_{C} =3.0 μ A I_{E} =10 μ A	30 15	10	nA μA V V
ICBO ICBO BVCBO BVCEO BVEBO VCE(SAT)	V_{CB} =15V V_{CB} =15V, T_{A} =150°C I_{C} =1.0 μ A I_{C} =3.0 μ A I_{E} =10 μ A	30 15	10 1.0	nA μA V V
ICBO ICBO BVCBO BVCEO BVEBO	V_{CB} =15V V_{CB} =15V, T_{A} =150°C I_{C} =1.0 μ A I_{C} =3.0 μ A I_{E} =10 μ A I_{C} =10 μ A, I_{B} =1.0 μ A	30 15	10 1.0	nA μA V V V
ICBO ICBO BVCBO BVCEO BVEBO VCE(SAT) VBE(SAT)	V_{CB} =15 V V_{CB} =15 V , T_{A} =150° C I_{C} =1.0 μ A I_{C} =3.0 m A I_{E} =10 μ A I_{C} =10 m A, I_{B} =1.0 m A	30 15 3.0	10 1.0	nA μA V V V
ICBO ICBO BVCBO BVCEO BVEBO VCE(SAT) VBE(SAT)	V_{CB} =15V V_{CB} =15V, T_{A} =150°C I_{C} =1.0 μ A I_{C} =3.0 μ A I_{E} =10 μ A I_{C} =10 μ A, I_{B} =1.0 μ A I_{C} =10 μ A, I_{B} =1.0 μ A I_{C} =10 μ A, I_{C} =3.0 μ A	30 15 3.0	10 1.0	nA μA V V V V
ICBO ICBO BVCBO BVCEO BVEBO VCE(SAT) VBE(SAT) hFE fT	V _{CB} =15V V _{CB} =15V, T _A =150°C I _C =1.0μA I _C =3.0mA I _E =10μA I _C =10mA, I _B =1.0mA I _C =10mA, I _B =1.0mA V _{CE} =1.0V, I _C =3.0mA V _{CE} =10V, I _C =4.0mA, f=100MHz	30 15 3.0	10 1.0 0.4 1.0	nA μA V V V V MHz

30

15

25

dB R1 (11-September 2012)

6.0

mW

dΒ

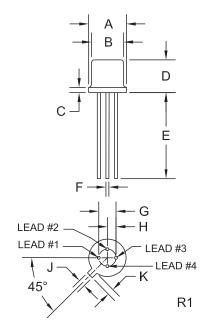
%

2N918

NPN SILICON RF TRANSISTOR



TO-72 CASE - MECHANICAL OUTLINE



DIMENSIONS							
	INCHES		MILLIMETERS				
SYMBOL	MIN	MAX	MIN	MAX			
A (DIA)	0.209	0.230	5.31	5.84			
B (DIA)	0.175	0.195	4.45	4.95			
С	-	0.030	-	0.76			
D	0.170	0.210	4.32	5.33			
E	0.500	-	12.70	-			
F (DIA)	0.016	0.019	0.41	0.48			
G (DIA)	0.100		2.54				
Н	0.050		1.27				
J	0.036	0.046	0.91	1.17			
K	0.028	0.048	0.71	1.22			

TO-72 (REV: R1)

LEAD CODE:

- 1) Emitter
- 2) Base
- 3) Collector 4) Case

MARKING: FULL PART NUMBER

OUTSTANDING SUPPORT AND SUPERIOR SERVICES



PRODUCT SUPPORT

Central's operations team provides the highest level of support to insure product is delivered on-time.

- Supply management (Customer portals)
- · Inventory bonding
- · Consolidated shipping options

- · Custom bar coding for shipments
- · Custom product packing

DESIGNER SUPPORT/SERVICES

Central's applications engineering team is ready to discuss your design challenges. Just ask.

- Free quick ship samples (2nd day air)
- Online technical data and parametric search
- SPICE models
- · Custom electrical curves
- · Environmental regulation compliance
- · Customer specific screening
- · Up-screening capabilities

- · Special wafer diffusions
- PbSn plating options
- · Package details
- · Application notes
- · Application and design sample kits
- Custom product and package development

CONTACT US

Corporate Headquarters & Customer Support Team

Central Semiconductor Corp. 145 Adams Avenue Hauppauge, NY 11788 USA Main Tel: (631) 435-1110 Main Fax: (631) 435-1824

Support Team Fax: (631) 435-3388

www.centralsemi.com

Worldwide Field Representatives: www.centralsemi.com/wwreps

Worldwide Distributors:

www.centralsemi.com/wwdistributors

For the latest version of Central Semiconductor's **LIMITATIONS AND DAMAGES DISCLAIMER**, which is part of Central's Standard Terms and Conditions of sale, visit: www.centralsemi.com/terms

www.centralsemi.com